

MPQ1922-AEC1/MP1922

100V, 3A, Half-Bridge Pre-Driver, AEC-Q100 Qualified

Q4 2021



MPQ1922-AEC1/MP1922 – Target Applications

- **Automotive Pumps and Fans**
- **Automotive Superchargers and Actuators**
- **Battery-Powered Tools**
- **E-Bikes**



Automotive Fans



Automotive Superchargers



Power Tools



E-Bikes

Why Use This Part?

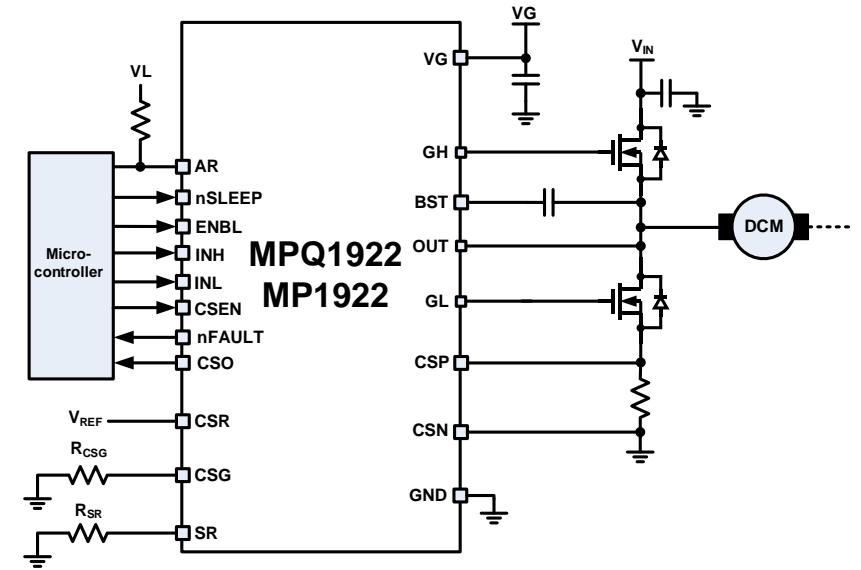
It's Simple and Easy!

- Supports 100V Operation Voltage with 3A Source, 4A Sink Gate Driver Current
- Integrated Current-Sense Amplifier
- Internal Charge Pump and Auto-Bootstrap (Auto-BST) Refresh
- External MOSFETs Provide Desaturation Protection and Shoot-Through Protection
- Configurable Slew Rate
- Available in AEC-Q100 Grade 1

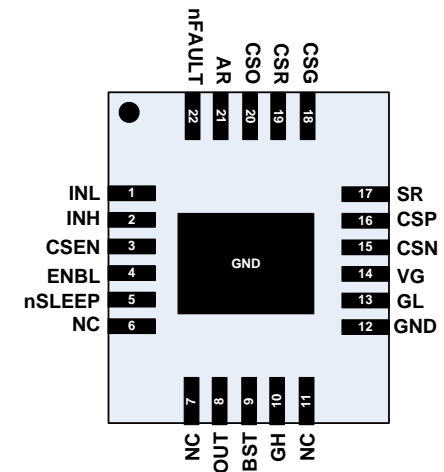
MPQ1922-AEC1/MP1922 – 100V, 3A, Half-Bridge Pre-Driver

FEATURES

- Supports 100V Supply
- 3A Source, 4A Sink Gate Driver Current
- Internal Charge Pump and Auto-Refresh for High-Side MOSFET (HS-FET) Gate Driver
- Integrated Current-Sense Amplifier
- Low-Power Sleep Mode
- Configurable Controlled Slew Rate
- External MOSFET Desaturation Protection
- Thermal Shutdown
- Under-Voltage Lockout (UVLO) Protection
- Fault Indication Output
- Thermally Enhanced Surface-Mount Package
- Available in a QFN-22 (4mmx5mm) Package



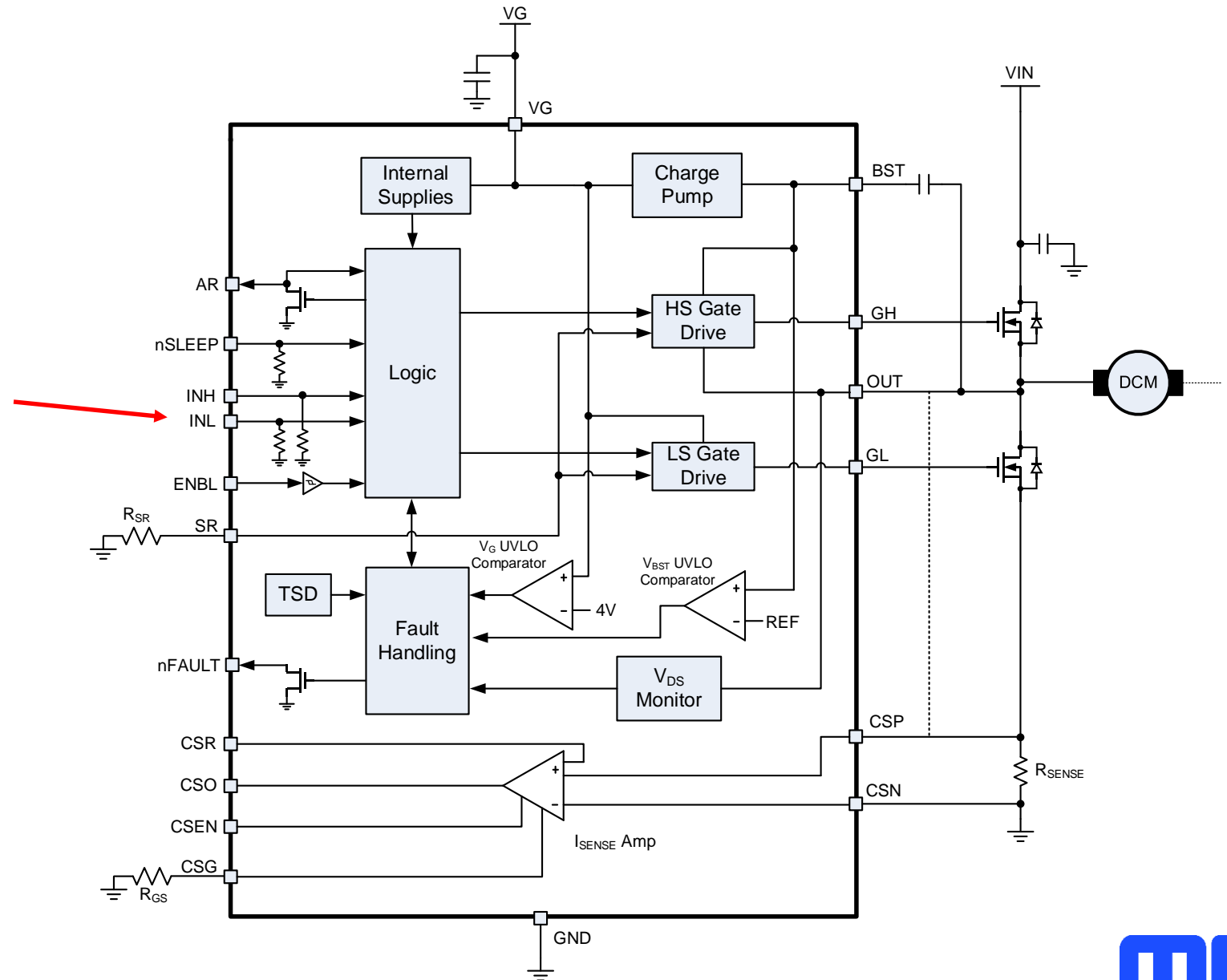
Available in a QFN-22 (4mmx5mm) Package



MPQ1922-AEC1/MP1922 – Functional Block Diagram

Input Logic

INL	INH	OUT
High	High	Hi-Z
High	Low	GND
Low	High	VIN
Low	Low	Hi-Z



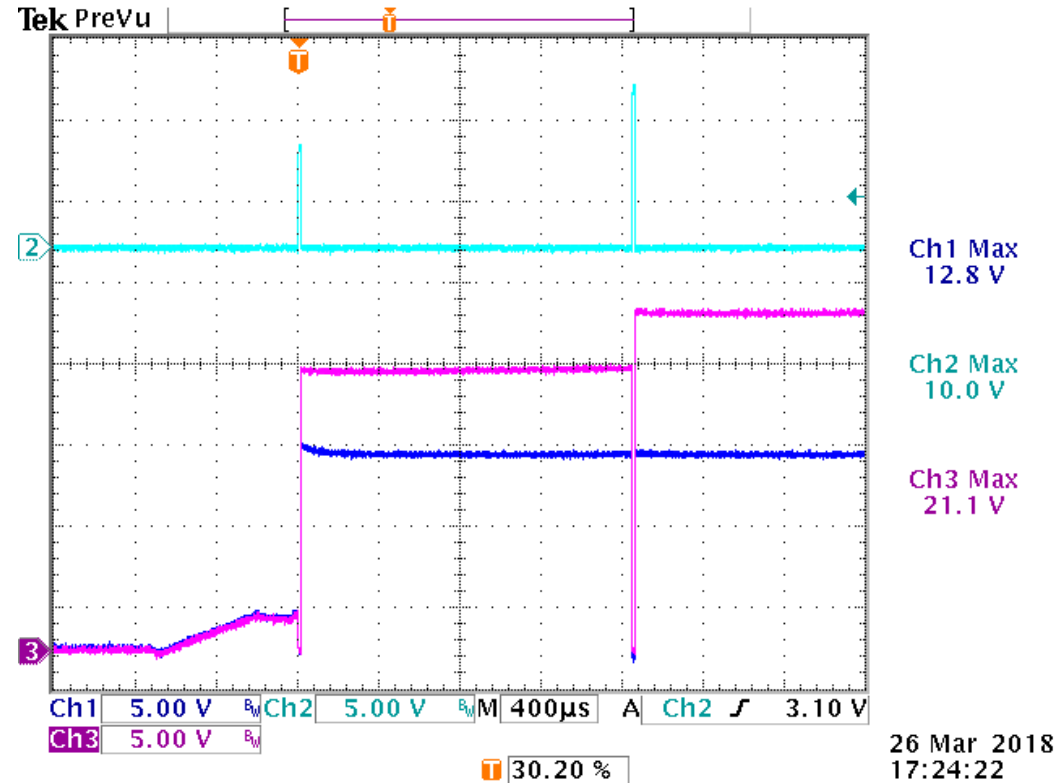
MPQ1922-AEC1/MP1922 – Slew Rate Control

- The MPQ1922-AEC1 and MP1922 employ configurable slew rate control to reduce electromagnetic interference (EMI) that is generated when the output switches quickly.
- The slew rate is controlled by changing the pull-up and pull-down resistance of the MOSFET gates, which can be set by the resistance between the SR pin and ground.

R_{SR}	Pull-Up Resistance	Pull-Down Resistance	Adaptative Dead Time
0Ω	1.8Ω	1.4Ω	No
$10k\Omega$	8Ω	3.7Ω	Yes
$30k\Omega$	25Ω	14Ω	Yes
$100k\Omega$	100Ω	42Ω	Yes

MPQ1922-AEC1/MP1922 – Bootstrap (BST) Refresh

If the BST voltage (V_{BST}) is insufficient, the low-side MOSFET (LS-FET) turns on.

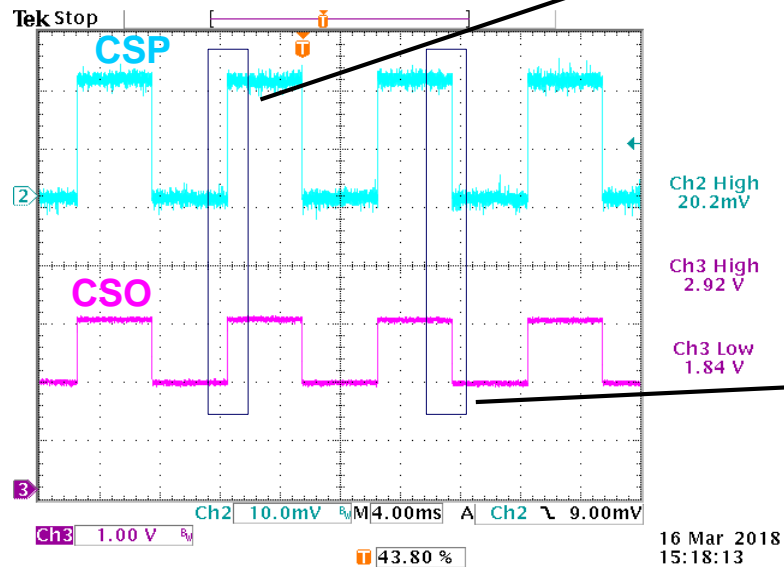


Test Conditions: $V_{IN} = 12V$, HS-FET is high, LS-FET is low,
no load, starts with $V_{GATE} = 12V$, AR is low

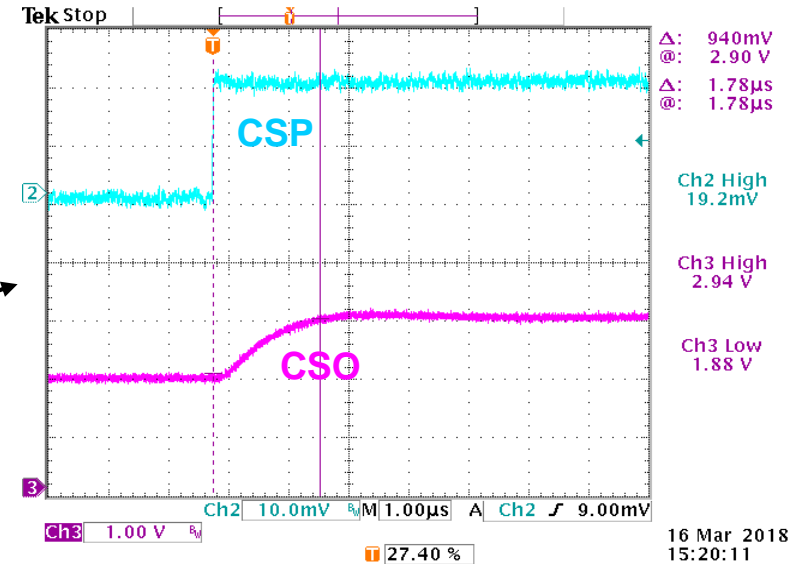
MPQ1922-AEC1/MP1922 – Current Sense

Current-Sense Gain

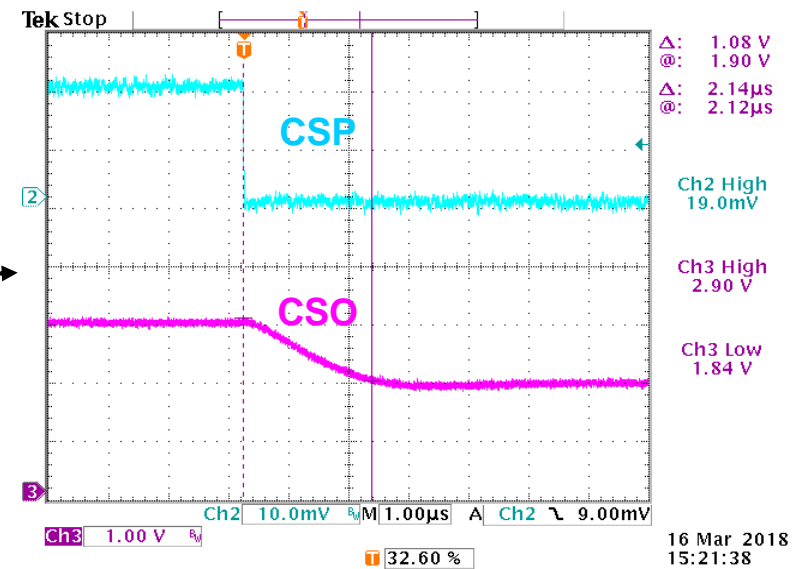
R_{CSG}	Gain
0 Ω	210
10k Ω	105
30k Ω	52.5
100k Ω	21



Zoom In



Zoom In



Test Conditions: $V_{CSR} = 1.7V$, $R_{CSG} = 30k\Omega$, Gain = 50V/V